

GaAs Monolithic MIC Mixer-IF Amplifiers for Direct Broadcast Satellite Receivers

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An MMIC mixer-IF amplifier (MIX-IFA) and a band-pass filter (BPF) have been developed for DBS receiver applications. The MIX-IFA chip with a size of $2.0 \times 2.25 \text{ mm}^2$ contains a balanced-type diode mixer using a newly designed 3-dB hybrid circuit and a resistive feedback-type single-stage IF amplifier. The MIX-IFA shows a noise figure of $\leq 72 \text{ dB}$ and a conversion gain of 1.5 dB for signal frequencies from 11.7 to 12.2 GHz with a minimum noise figure of 9 dB and a maximum conversion gain of 3.5 dB. All the circuit elements such as Schottky diodes, FET and resistors are fabricated in a planar structure by using selective ion-implantation technology for realizing good uniformity and reproducibility. The BPF chip designed from modification of high-pass filter exhibits an insertion loss of $\leq 1 \text{ dB}$ for signals and an attenuation of $\geq 10 \text{ dB}$ for images. With the previously developed LNA, IFA and local oscillator, all MMIC components for DBS receiver are prepared.

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